

View Online at <https://aerobasegroup.com/nsn/5961-01-370-1945>

Internal Configuration:

Junction contact

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

3.5 breakdown voltage, emitter-to-base, collector open and 65.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 25.0 breakdown voltage, collector-to-emitter, base open and 65.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

10.00 milliamperes zero-gate-voltage source current preset

Power Rating Per Characteristic:

200.0 watts large-signal output power, common-collector universal

Transfer Ratio:

5.0 static forward current transfer ratio, common-emitter and 200.0 static forward current transfer ratio, common-emitter

Special Features:

Junction pattern arrangement: npn

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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